### Giant nonlinearity via breaking parity-time symmetry: A route to low-threshold phonon diodes

Jing Zhang, <sup>1,2,3,\*</sup> Bo Peng, <sup>3</sup> Şahin Kaya Özdemir, <sup>3,†</sup> Yu-xi Liu, <sup>2,4,‡</sup> Hui Jing, <sup>5,6</sup> Xin-you Lü, <sup>6,7</sup> Yu-long Liu, <sup>4</sup>
Lan Yang, <sup>3,§</sup> and Franco Nori<sup>6,8,||</sup>

<sup>1</sup>Department of Automation, Tsinghua University, Beijing 100084, P. R. China
<sup>2</sup>Center for Quantum Information Science and Technology, TNList, Beijing 100084, P. R. China
<sup>3</sup>Department of Electrical and Systems Engineering, Washington University, St. Louis, Missouri 63130, USA
<sup>4</sup>Institute of Microelectronics, Tsinghua University, Beijing 100084, P. R. China
<sup>5</sup>Department of Physics, Henan Normal University, Xinxiang 453007, P. R. China
<sup>6</sup>CEMS, RIKEN, Saitama 351-0198, Japan

<sup>7</sup>School of physics, Huazhong University of Science and Technology, Wuhan 430074, China <sup>8</sup>Physics Department, The University of Michigan, Ann Arbor, Michigan 48109-1040, USA (Received 27 April 2015; revised manuscript received 11 August 2015; published 8 September 2015)

Nonreciprocal devices that permit wave transmission in only one direction are indispensible in many fields of science including, e.g., electronics, optics, acoustics, and thermodynamics. Manipulating phonons using such nonreciprocal devices may have a range of applications such as phonon diodes, transistors, switches, etc. One way of achieving nonreciprocal phononic devices is to use materials with strong nonlinear response to phonons. However, it is not easy to obtain the required strong mechanical nonlinearity, especially for few-phonon situations. Here we present a general mechanism to amplify nonlinearity using parity-time  $(\mathcal{PT})$ -symmetric structures, and show that an on-chip microscale phonon diode can be fabricated using a  $\mathcal{P}\mathcal{T}$ -symmetric mechanical system, in which a lossy mechanical resonator with very weak mechanical nonlinearity is coupled to a mechanical resonator with mechanical gain but no mechanical nonlinearity. When this coupled system transits from the  $\mathcal{P}\mathcal{T}$ -symmetric regime to the broken-PT-symmetric regime, the mechanical nonlinearity is transferred from the lossy resonator to the one with gain, and the effective nonlinearity of the system is significantly enhanced. This enhanced mechanical nonlinearity is almost lossless because of the gain-loss balance induced by the  $\mathcal{PT}$ -symmetric structure. Such an enhanced lossless mechanical nonlinearity is then used to control the direction of phonon propagation, and can greatly decrease (by over three orders of magnitude) the threshold of the input-field intensity necessary to observe the unidirectional phonon transport. We propose an experimentally realizable lossless low-threshold phonon diode of this type. Our study opens up perspectives for constructing on-chip few-phonon devices and hybrid phonon-photon components.

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#### I. INTRODUCTION

Owing to recent progress in nanotechnology and materials science, nano- and micromechanics [1-7] have emerged as subjects of great interest due to their potential use in demonstrating macroscopic quantum phenomena, and possible applications in precision measurements, detecting gravitational waves, building filters, signal amplification, as well as switches and logic gates. In particular, on-chip single- or few-phonon devices are ideal candidates for hybrid quantum information processing, due to the ability of phonons to interact and rapidly switch between optical fields and microwave fields [8,9]. Fabrication of high-frequency mechanical resonators [10], demonstration of coherent phonon coupling between nanomechanical resonators [11], ground-state cooling [12,13], and optomechanics (in microtoroids [14,15], microspheres [16–18], microdisks [19–21], microring [22], photonic crystals [11], doubly or singly clamped cantilevers [23,24], and membranes [25]) have opened new directions [5] and provided new tools to control and manipulate phonons in on-chip devices. One possible obstacle to further develop this field is the ability to control the flow of phonons, allowing transport in one direction but not the opposite direction [26], i.e., nonreciprocal phonon transport. There have been several attempts to fabricate nonreciprocal devices for phonons [27–32], but these are almost exclusively based on asymmetric linear structures which indeed cannot break Lorentz reciprocity: a static linear structure cannot break reciprocity [27]. These proposed linear structures do obey the reflection-transmission reciprocity and thus cannot be considered as "phonon diodes." Diodelike behavior was observed in these linear acoustic structures because the input-output channels were not properly switched [27].

Nonreciprocal phonon transmission inevitably requires magnetoacoustic materials, strong nonlinearity, or a time-dependent modulation of the parameters of a structure. Although already demonstrated in optics [33], the time-dependent modulation of acoustic parameters of a phononic structure has not been probed yet. Magnetoacoustic materials require high magnetic fields to operate and have been studied [34]; however, a magnetic-free nonreciprocal device is critical for building on-chip and small-scale phononic processors and circuits. Nonlinearity-based nonreciprocity seems to be the most viable approach for creating micro- or nanoscale nonreciprocal devices for controlling and manipulating phonons.

<sup>\*</sup>jing-zhang@mail.tsinghua.edu.cn

<sup>†</sup>ozdemir@ese.wustl.edu

<sup>‡</sup>yuxiliu@mail.tsinghua.edu.cn

<sup>§</sup>yang@ese.wustl.edu

<sup>¶</sup>fnori@riken.jp

Recently there have been several reports on nonlinear mechanical structures and materials [35–38]. However, the weak nonlinearity of those acoustic/phononic materials hinders progress in this direction due to the high input powers required to observe the nonlinear effects [39,40]. In order to circumvent this problem, coupling a weakly nonlinear structure to an auxiliary system, such as a quantum bit [41], has been proposed to engineer effective giant mechanical nonlinearities.

In order to achieve the required nonlinearity for nonreciprocal phonon transport and to study nonlinear phononics, here we introduce a method based on parity-time ( $\mathcal{PT}$ ) symmetry [42], which has attracted much attention recently due to their interesting and generally counterintuitive physics [43–68]. Parity-time symmetry and its breaking (broken  $\mathcal{PT}$  phase) have been demonstrated in various physical systems [52–64], such as optical waveguides [52–55], microcavities [62], and electrical circuits [57]. However, mechanical  $\mathcal{PT}$ -symmetric systems have only been considered quite recently [64–68].

In our proposed mechanical  $\mathcal{PT}$ -symmetric system, a lossy mechanical resonator (passive resonator) which has a weak mechanical nonlinearity is coupled to a mechanical resonator with mechanical gain (active resonator) that balances the loss of the passive resonator. The active resonator here works as a dynamical amplifier. In the vicinity of the  $\mathcal{PT}$ -phase transition, the weak nonlinearity is first distributed between the mechanically coupled resonators and then significantly enhanced due to the localization of the mechanical supermodes in the active resonator. In this way, the effective nonlinear Kerr coefficient is increased by over three orders of magnitude. This strong nonlinearity, localized in the active resonator, blocks the phonon transport from the active resonator to the lossy resonator but permits the transport in the opposite direction.

For the experimental realization of the proposed nonlinearity-based phonon diode, we provide a system in which a mechanical beam with weak mechanical nonlinearity is coupled to another mechanical beam with gain. We show that this microscale system can be switched from a bidirectional transport regime to a unidirectional transport regime, and vice versa, by properly adjusting the detuning between the mechanical frequency of the resonators and the frequency of the driving phononic field, or by varying the amplitude of the input phononic field.

# II. PARITY-TIME ( $\mathcal{PT}$ -) SYMMETRIC MECHANICAL SYSTEM

The system we consider here consists of two mechanical resonators, one of which has mechanical loss (passive resonator) and weak nonlinearity, and the other has mechanical gain (active resonator) but no nonlinearity (see Fig. 1). The mechanical coupling between the resonators is linear and it gives rise to the mechanical supermodes  $b_{\pm}$  with complex eigenfrequencies

$$\omega_{\pm} = \Omega_{\pm} - i \Gamma_{\pm},\tag{1}$$

given by

$$\omega_{\pm} = \Omega_0 - i\chi \pm \beta. \tag{2}$$

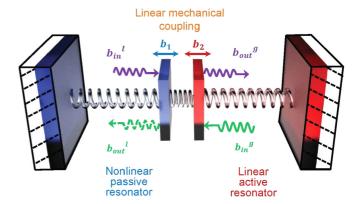


FIG. 1. (Color online) Schematic diagram of the proposed  $\mathcal{P}T$ -symmetric mechanical system. The  $\mathcal{P}T$ -symmetric mechanical system has a linear mechanical coupling between a passive mechanical resonator (having mechanical loss and very weak mechanical nonlinearity) and an active mechanical resonator (having mechanical gain but no nonlinearity). Here  $b_{\rm in}^l$  and  $b_{\rm in}^g$  are the input fields to the passive and active resonators, respectively, and  $b_{\rm out}^l$  and  $b_{\rm out}^g$  are the output fields, respectively, leaving the passive and active resonators.  $b_1$  and  $b_2$  denote the movable resonators.

Here  $\Omega_0$  is the mechanical frequency of the solitary mechanical resonators (i.e., both resonators are degenerate),

$$\chi = (\Gamma_l - \Gamma_g)/2,\tag{3}$$

$$\beta = \sqrt{g_{mm}^2 - \Gamma^2},\tag{4}$$

$$\Gamma = (\Gamma_l + \Gamma_g)/2,\tag{5}$$

where  $\Gamma_l$  and  $\Gamma_g$  denote, respectively, the damping rate of the lossy mechanical resonator and the gain rate of the active mechanical resonator, and  $g_{mm}$  is the coupling strength between the mechanical modes. When  $\Gamma \leqslant g_{mm}$ , the system is in the  $\mathcal{PT}$ -symmetric regime, and the supermodes are nondegenerate with

$$\Omega_{\pm} = \Omega_0 \pm \beta \tag{6}$$

and have the same damping rate  $\chi$  [see Figs. 2(a) and 2(b)]. However, when  $\Gamma > g_{mm}$ , the system is in the broken- $\mathcal{PT}$ -symmetric regime, the supermodes are frequency degenerate with  $\Omega_{\pm} = \Omega_0$  [see Figs. 2(a) and 2(b)] and have different damping rates

$$\Gamma_{+} = \chi \mp i\beta. \tag{7}$$

At  $\Gamma = g_{mm}$ , the two supermodes are degenerate with the same damping rate, indicating a transition between the  $\mathcal{P}\mathcal{T}$ -symmetric regime and the broken- $\mathcal{P}\mathcal{T}$ -symmetry regime. This point is generally referred to as the  $\mathcal{P}\mathcal{T}$ -transition point. It is seen that the two supermodes will be lossless in the  $\mathcal{P}\mathcal{T}$ -symmetric regime if the gain and loss are well balanced, such that  $\Gamma_l = \Gamma_g$ .

# III. ENHANCING MECHANICAL NONLINEARITY BY BREAKING $\mathcal{P}\mathcal{T}$ SYMMETRY

Let us assume that the passive resonator is made from a nonlinear acoustic material [35] with a small nonlinear

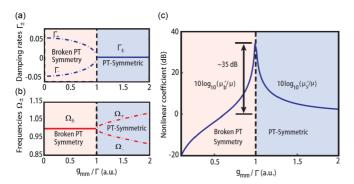


FIG. 2. (Color online) Amplification of mechanical nonlinearity via  $\mathcal{P}T$ -symmetry breaking. (a) Effective damping rates and (b) frequencies of the mechanical supermodes as functions of the normalized mechanical coupling strength  $g_{mm}/\Gamma$ . (c) The effective nonlinear coefficients  $\mu_b'$  in the  $\mathcal{P}T$ -breaking regime and  $\mu_s'$  in the  $\mathcal{P}T$ -symmetric regime. The  $\mathcal{P}T$ -phase transition takes place at  $g_{mm} = \Gamma$ . In the vicinity of this transition point, the nonlinear coefficients  $\mu_b'$  and  $\mu_s'$  are enhanced by more than three orders of magnitude (more than 35 dB increase compared to the baseline).

Kerr coefficient  $\mu$ . This nonlinearity mediates a cross-Kerr interaction between the two mechanical supermodes, which leads to the effective nonlinear coefficients  $\mu_b'$  and  $\mu_s'$ , in the broken- and unbroken- $\mathcal{PT}$  regimes:

$$\mu_b' = \mu \frac{\Gamma^2 g_{mm}^2}{\left(\Gamma^2 - g_{mm}^2\right)^2}, \quad \mu_s' = \mu \frac{g_{mm}^4}{\left(\Gamma^2 - g_{mm}^2\right)^2}.$$
 (8)

Clearly the effective nonlinear coefficients are significantly enhanced in the vicinity of the phase transition point  $\Gamma = g_{mm}$  [see Fig. 2(c)]. Moreover, if the gain and loss are well balanced, i.e.,  $\Gamma_l = \Gamma_g$ , the supermodes become almost lossless. This observation is one of the key contributions of this paper. Namely, operating the system of two coupled mechanical resonators in the vicinity of the phase transition point will significantly enhance the existing very weak nonlinearity with an extremely small loss rate.

Using the parameter values of  $\mu/\Omega_0 = 10^{-5}$ ,  $\Gamma_l/\Omega_0 = 0.55 \times 10^{-3}$ , and  $\Gamma_g/\Omega_0 = 0.45 \times 10^{-3}$ , we show in Fig. 2 the evolution of the eigenfrequencies of the system and of the nonlinear coefficient as a function of  $g_{mm}/\Gamma$ . The transition from the broken- to the unbroken- $\mathcal{PT}$ -symmetric regime and vice versa, as the mechanical coupling strength is varied, is seen in Figs. 2(a) and 2(b) and it is reflected in the bifurcations of the supermode frequencies and damping rates. Moreover, the enhancement of the nonlinearity in the vicinity of the  $\mathcal{PT}$ -phase transition point is seen in Fig. 2(c). We find that the nonlinear coefficient is enhanced by more than three orders of magnitude in the vicinity of the transition point.

More interestingly, in the broken- $\mathcal{PT}$  regime, the mechanical energy of the coupled system is localized in the active resonator, which leads to a nonlinear mechanical mode with strong self-Kerr nonlinearity localized in the active mechanical resonator. This can be interpreted intuitively as follows. The initial weak mechanical nonlinearity is transferred from the passive resonator to the active resonator and it is enhanced by field localization in the broken- $\mathcal{PT}$  regime. Owing to the presence of the mechanical gain, the active resonator

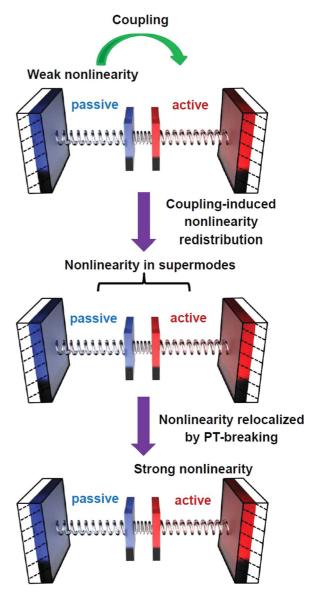


FIG. 3. (Color online) Enhancement of mechanical nonlinearity in a  $\mathcal{P}\mathcal{T}$ -symmetric mechanical system. The coupling between two mechanical resonators creates two mechanical supermodes symmetrically distributed between the resonators, and hence both supermodes experience the weak nonlinearity of the passive resonator. In the vicinity of the  $\mathcal{P}\mathcal{T}$ -phase transition, which takes place when the coupling strength between the resonators equals to the total loss in the system, the mechanical nonlinearity is significantly enhanced due to localization of the mechanical supermodes in the active mechanical resonator.

then enjoys an almost lossless mechanical mode with a giant nonlinearity (see Fig. 3).

Finally, we would like to consider how the mechanical nonlinearity will affect the  $\mathcal{P}\mathcal{T}$ -symmetric structure of the system. Generally speaking, a strong nonlinearity will shift the transition point of a  $\mathcal{P}\mathcal{T}$ -symmetric system or even destroy the  $\mathcal{P}\mathcal{T}$  symmetry of such a system [69]. However, in our case, we start from a system in which a gain resonator is coupled to a lossy resonator with very weak Kerr nonlinearity, and thus we can omit the shift of the  $\mathcal{P}\mathcal{T}$ -transition point induced by such a

weak nonlinearity. Although we generate a strong nonlinearity in the vicinity of the  $\mathcal{P}\mathcal{T}$ -transition point, this is an effective nonlinearity induced in the supermode picture and thus will not affect the supermodes and the  $\mathcal{P}\mathcal{T}$ -transition point of the system.

#### IV. UNIDIRECTIONAL PHONON TRANSPORT

Here we investigate the effect of the enhanced mechanical nonlinearity on the phonon transport in the coupled system. We find that the localized strong mechanical nonlinearity leads to unidirectional phonon transport from the passive resonator to the active resonator and blocks phonon transport in the opposite direction (i.e., phonon transport from the active to the passive resonator is prevented). The transport is almost lossless due to the gain-loss balance of the system. When this system is operated in the vicinity of the  $\mathcal{PT}$ -phase transition point, the unidirectional phonon transport is possible within a region given by

$$\delta \in \left[ \frac{g_{mm}^2 \Omega_0}{\Omega_0^2 + \chi^2}, \frac{g_{mm}^2}{\Omega_0 - \sqrt{3} \chi} \right], \tag{9}$$

where

$$\delta = \Omega_0 - \Omega_d \tag{10}$$

is the detuning between the input (driving) field frequency  $\Omega_d$  and the resonance frequency  $\Omega_0$  of the mechanical resonators. Additionally, in order to observe the unidirectional phonon transport, the amplitude of the input field should satisfy

$$|\varepsilon_d|^2 \in \left[\frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'\delta^3}, \frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'g_{mm}^2\delta}\right],$$
 (11)

implying that the intensity of the input field required for unidirectional transport is inversely proportional to the strength of the mechanical nonlinearity  $\mu_b'$ . Since the strength of the mechanical nonlinearity can be enhanced by more than three orders of magnitude by breaking the  $\mathcal{PT}$  symmetry, the threshold of the input-field intensity for observing unidirectional phonon transport can be decreased by at least three orders of magnitude, allowing a low-threshold phonon diode operation.

To show unidirectional phonon transport in the broken- $\mathcal{PT}$  regime, let us first fix the amplitude of the input field and vary the detuning  $\delta$ . We compare the amplitude transmittance

$$t_{l\to g} = b_{\text{out}}^g / b_{\text{in}}^l \tag{12}$$

and

$$t_{g \to l} = b_{\text{out}}^l / b_{\text{in}}^g. \tag{13}$$

The former,  $t_{l \to g}$ , denotes the transmission from the passive to the active resonator, that is, the system is driven by a phononic input field  $b_{\rm in}^l$  of frequency  $\Omega_d$  at the passive resonator side and the output  $b_{\rm out}^g$  is measured at the active resonator side. However, the latter,  $t_{g \to l}$ , denotes the amplitude transmittance from the active resonator to the passive resonator when the system is driven by the field  $b_{\rm in}^g$  of frequency  $\Omega_d$  at the active resonator side and the output  $b_{\rm out}^l$  is measured at the passive side. The nonlinearity in the system manifests as a bistability and hysteresis in the power transmittance,

$$T_{g \to l} = |t_{g \to l}|^2 \tag{14}$$

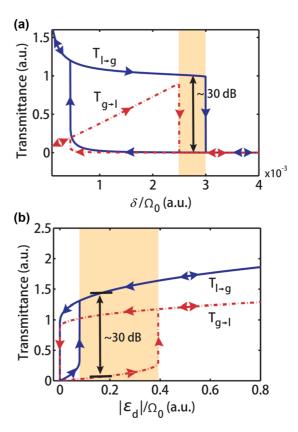


FIG. 4. (Color online) Unidirectional phonon transport by  $\mathcal{P}T$ -symmetry breaking. (a) Unidirectional phonon transport when the detuning  $\delta$  is varied. The transmittance from the active to passive mechanical resonator  $T_{g \to l}$  (red dash-dotted curve), and from the passive to the active mechanical resonator  $T_{l \to g}$  (blue solid curve) versus the detuning  $\delta = \Omega_0 - \Omega_d$  shows a strong bistability and hysteresis effect. The transmittance functions evolve along different trajectories for increasing and decreasing detuning due to the nonlinearity-induced bistability. A unidirectional phonon-transport region (melon-colored shaded region) appears only when the detuning  $\delta$  is up-scanned from smaller to larger detunings. Within this regime, the rectification is  $\sim 30$  dB. (b) Unidirectional photon transport when the amplitude of the input field is varied at fixed detuning  $\delta/\Omega_0 = 2.75 \times 10^{-3}$ . Within the unidirectional transport region (melon-colored shaded region), rectification is  $\sim 30$  dB.

and

$$T_{l \to \varrho} = |t_{l \to \varrho}|^2, \tag{15}$$

obtained as the detuning  $\delta$  is up-scanned from smaller to larger detuning and down-scanned from larger to smaller detuning [see Fig. 4(a)].

We find that during the down-scan, both of the transmittances  $T_{l \to g}$  and  $T_{g \to l}$  stay at the lower branch with values close to zero until  $\delta/\Omega_0 = 0.5 \times 10^{-3}$ , after which they bifurcate from each other only slightly and then jump to the stable points at the upper branch of their respective trajectories [see Fig. 4(a)]. Further decreasing the detuning leads to an increase in  $T_{l \to g}$ , but a decrease in  $T_{g \to l}$ . This implies that there is no unidirectional phonon transport with the parameter values used in the numerical simulations. Instead, when the detuning is below a critical value, the phonon transport is bidirectional;

whereas when it is above that critical value there is no phonon transport.

During the up-scan, however, after a short stay on the stable state, i.e., a regime in which there is no bistability and hysteresis in the transmittance (during which  $T_{l\to g}$  decreases and  $T_{g\rightarrow l}$  increases with growing detuning), both of the transmittances follow the upper branches of their trajectories, during which a linear increase in  $T_{g\rightarrow l}$  and a slow-rate decrease in  $T_{l\to g}$  are observed [see Fig. 4(a)]. This behavior continues until  $\delta/\Omega_0 \sim 2.5 \times 10^{-3}$  for  $T_{g \to l}$ , where it jumps to the lower branch of its trajectory, and becomes zero as the detuning is increased [see Fig. 4(a)]. This implies that phonon transport from the active mechanical resonator to the passive one is prevented if the detuning is set to  $\delta/\Omega_0 > 2.5 \times 10^{-3}$ . The transmittance  $T_{l\to g}$  stays at its upper branch with a value close to one until  $\delta/\Omega_0 \sim 3 \times 10^{-3}$ , where it jumps to its lower branch and becomes zero. Thus, for  $\delta/\Omega_0 > 3 \times 10^{-3}$ , phonon transport from the passive to the active resonator is prevented. Clearly, in the detuning region  $2.5 \times 10^{-3}$  $\delta/\Omega_0 < 3 \times 10^{-3}$ , the transmittance  $T_{l\to g}$  is close to one, whereas  $T_{g\rightarrow l}$  is close to zero in this detuning region, phonon transport from the active mechanical resonator to the passive one is forbidden, whereas phonon transport from the passive mechanical resonator to active one is allowed with almost no loss. Thus, we conclude that phonon transmission is nonreciprocal in this detuning region, and the rectification is  $\sim$ 30 dB within the nonreciprocal transport region [see Fig. 4(a)]. For detuning values smaller than the lower bound of this region, phonon transport is bidirectional. For detuning values larger than the upper bound of the region, phonon transport is not possible.

Note that our phonon diode should work only when the disturbance and perturbation of the system parameters are not too strong. In fact, within the unidirectional phonon transport window shown in Fig. 4(a), the transmittance  $T_{l \to g}$  has two different branches of metastable values. When we increase the detuning  $\delta$  within this unidirectional phonon transport window,  $T_{l \to g}$  will stay in the upper stable branch if we do not severely disturb the system and the phonon diode should operate properly. However, if the disturbance is too strong,  $T_{l \to g}$  will jump from the upper branch to the lower branch and stay in this stable lower branch, without rectification.

Alternatively, we can fix the detuning and vary the amplitude of the input field to show the nonlinearity-induced bistability and hysteresis. A nonreciprocal phonon transport region is seen when the amplitude of the input field is up-scanned [see Fig. 4(b)]. The nonreciprocal transport region disappears when the amplitude of the input field is downscanned. Within the nonreciprocal transport region, when the input is varied at fixed detuning [see Fig. 4(b)], the rectification is  $\sim$ 30 dB. Similarly, in this case, due to the metastability of the transmittance  $T_{l\rightarrow g}$ , the disturbance-induced perturbation of the system parameters may not be too strong otherwise our design of phonon diode will be invalid.

### V. ON-CHIP PHONON DIODE

The unidirectional phonon transport enabled by the  $\mathcal{P}\mathcal{T}$ -breaking-induced strong mechanical nonlinearity can be used to fabricate lossless phonon diodes in on-chip systems. This

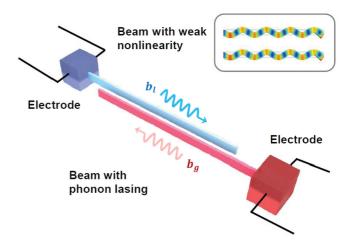


FIG. 5. (Color online) Schematic diagram of the phonon diode system with two mechanical beams in which a beam with weak mechanical nonlinearity is electrically or elastically coupled to another beam with mechanical gain. The insets show the finite-element-method (FEM) simulation by Comsol for the mechanical modes.

may have many applications, such as single-phonon transistors and routers, on-chip quantum switches, and information-processing components. One possible way to realize the proposed phonon diode is to use coupled beams and cantilevers [see Fig. 5(a)]. Phonon lasing, and hence an active mechanical resonator, has been experimentally realized in an electromechanical beam [70]. Elastically coupled nanobeams and cantilevers, by which the mechanical supermodes can be generated, have also been shown in various experiments [71–74], in which the two mechanical resonators can be independently driven [72]. Thus our proposal is within the reach of current experimental techniques of nano-microelectromechanical systems.

Let us now consider the design of the phonon diode system shown in Fig. 5 in which a lossy vibrating beam with damping rate  $\Gamma_l$  and a weak Kerr nonlinearity [35] of strength  $\mu$  is elastically coupled to another vibrating beam with gain  $\Gamma_g$  [70]. The frequencies of the two beams are both  $\Omega_0$  and the mechanical coupling strength is  $g_{mm}$ .

In Fig. 6 we present the numerical results performed with the system parameters:  $\Omega_0 = 600$  kHz,  $\Gamma_l = 33$  kHz,  $\Gamma_g =$ 30 kHz,  $\delta=1.65$  kHz,  $\mu=5.7$  kHz, and  $g_{mm}=1$  kHz. Here we fix the detuning  $\delta$  and change the amplitude of the input field. There is a 50 dB background noise which includes the combined effect of the thermal noise on the mechanical resonators, the electrical noises induced by the measurement apparatus, and other possible sources of noise. The results shown in Fig. 6 for the phonon diode agree well with the general model discussed in the previous section. When the amplitude of the input field is increased, it is clearly seen that there is a nonreciprocal region in which phonon transport from the active beam to the passive beam is almost completely suppressed [see Fig. 6(b)(ii)], but phonon transport from the passive beam to the active beam is allowed [see Fig. 6(a)(ii)]. A rectification ratio of about 30 dB is obtained. When the amplitude of the phonon excitation is larger than the upper bound of the unidirectional phonon transport region, the

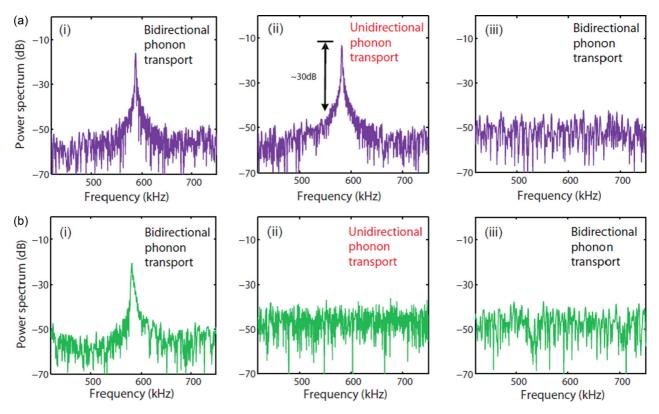


FIG. 6. (Color online) Numerical results demonstrating unidirectional phonon transport in a  $\mathcal{PT}$ -symmetric mechanical system in the broken- $\mathcal{PT}$  phase. (a) Power spectrum obtained at the output of the active beam without mechanical nonlinearity when the phonon excitation (input) is at the passive beam with weak nonlinearity. (b) Power spectrum obtained at the output of the passive beam when the phonon excitation (input) is at the active beam. When the intensity of the phonon excitation is within the region bounded by Eq. (11), phonon transport is unidirectional. Transport from the passive to the active resonator is allowed [see (a)(ii)], but the transport from the active to the passive resonator is prevented [(b)(ii)]. The rectification is about 30 dB. If the intensity of the phonon excitation is larger than the upper bound of the unidirectional transport region, phonon transport is bidirectional [(a)(i) and (b)(ii)]. Phonon transport is not allowed in either of the directions [(a)(iii) and (b)(iii)] if the intensity of the phonon excitation is smaller than the lower bound of the region given in Eq. (11).

transport is bidirectional. In this case, the phonons can freely move from the active beam to the passive beam and vice versa [see Figs. 6(a)(i) and 6(b)(i)]. Finally, for amplitudes of the phonon excitation smaller than the lower bound of the region, no phonon transport can take place between the resonators [see Figs. 6(a)(iii) and 6(b)(iii)]. These are the result of hysteresis [see Fig. 4(b)] caused by the strong mechanical nonlinearity.

### VI. DISCUSSIONS

We have proposed a method to generate ultrastrong mechanical nonlinearity with a very low-loss rate using a  $\mathcal{PT}$ -symmetric mechanical structure in which a mechanical resonator with gain but no nonlinearity is coupled to a lossy (i.e., passive mechanical loss and no gain) mechanical resonator with very weak nonlinearity. We have showed that the weak mechanical nonlinearity is redistributed in the supermodes of the coupled mechanical system and is enhanced (by more than three orders of magnitude) when the mechanical  $\mathcal{PT}$  system enters the broken- $\mathcal{PT}$  regime. Moreover, owing to the presence of the mechanical gain in one of the resonators to compensate the mechanical loss of the other resonator, the effective mechanical damping rate is decreased in the  $\mathcal{PT}$ -symmetric system. Using experimentally accessible parameter values, we identified the regimes where

unidirectional phonon transport is possible from the passive to active resonator but not in the opposite direction. We then proposed an experimentally realizable system where a mechanical beam with passive loss and weak nonlinearity is coupled to another beam which acts like an active mechanical resonator. A possible bottleneck for this design to achieve a phonon diode operated in ambient condition is whether the mechanical gain observed with the mechanical beams in a controlled environment and at low temperatures [36] could also be obtained in ambient-temperature conditions. A possible way to overcome this problem, and to realize phonon diodes in ambient conditions, is to use a hybrid system composed of a gain optomechanical resonator and an nonlinear electrically driven mechanical beam [35], where the coupling between them is achieved via the evanescent optical field of the optomechanical resonator [75]. The mechanical gain of the optomechanical resonators can be provided at ambient conditions by, e.g., the optomechanical dynamical instability in the blue detuning regime [76], which has been demonstrated in optomechanical resonators in various experiments [77]. Since creating strongly nonlinear mechanical or acoustic materials remains challenging, we believe that the proposed system and the developed approach provide a suitable platform for investigating nonlinear phononics and can be used as a building block to design more complex hybrid optomechanical or electromechanical information processors. We envision that  $\mathcal{P}\mathcal{T}$  mechanical systems will open a new route for designing functional phononic systems with nonreciprocal phonon responses.

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# APPENDIX A: NONLINEARITY ENHANCEMENT BY BROKEN $\mathcal{PT}$ SYMMETRY

In order to prove the enhancement of mechanical nonlinearity in the broken- $\mathcal{P}T$ -symmetric regime, let us consider a system of two coupled mechanical resonators, in which one of the resonators has mechanical gain (active resonator) and thus a positive damping rate  $\Gamma_g$  and the second mechanical resonator has a passive mechanical loss (passive resonator) with loss rate  $\Gamma_l$ . The resonators have the same mechanical frequency  $\Omega_0$ , and the annihilation operators for their mechanical modes are denoted as  $b_g$  and  $b_l$ , respectively, for the active and passive resonators. Moreover, the passive mechanical resonator has a weak mechanical Kerr nonlinearity denoted by  $\mu$ . The Hamiltonian describing these coupled mechanical resonators can be written as

$$H = (\Omega_0 - i\Gamma_l)b_l^{\dagger}b_l + (\Omega_0 + i\Gamma_g)b_g^{\dagger}b_g$$
$$+ g_{mm}(b_l^{\dagger}b_g + b_lb_g^{\dagger}) + \mu(b_l^{\dagger}b_l)^2, \tag{A1}$$

where  $g_{mm}$  is the coupling strength between the mechanical modes of the resonators. Generally the nonlinear Kerr term in Eq. (A1) will shift the boundary between the  $\mathcal{PT}$  symmetric regime and the broken- $\mathcal{PT}$  regime. However, in our model, the Kerr nonlinearity denoted by  $\mu$  is very weak, and we can omit the nonlinearity-induced shift of this boundary. To find the boundary of  $\mathcal{PT}$  transition, we consider the first three terms in Eq. (A1),

$$H_1 = (\Omega_0 - i\Gamma_l)b_l^{\dagger}b_l + (\Omega_0 + i\Gamma_g)b_g^{\dagger}b_g + g_{mm}(b_l^{\dagger}b_g + b_lb_g^{\dagger}), \tag{A2}$$

which can be written as

$$H_1 = (b_g^{\dagger} \quad b_l^{\dagger}) \begin{pmatrix} \Omega_0 + i \Gamma_g & g_{mm} \\ g_{mm} & \Omega_0 - i \Gamma_l \end{pmatrix} \begin{pmatrix} b_g \\ b_l \end{pmatrix}. \tag{A3}$$

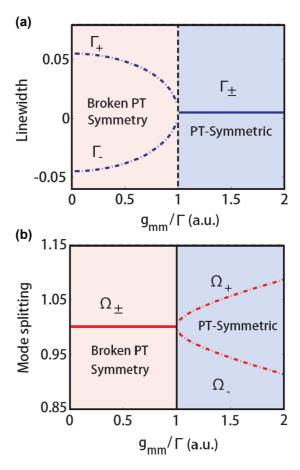


FIG. 7. (Color online) Evolution of the eigenfrequencies of the coupled mechanical resonators. (a) Difference of the real parts of the eigenfrequencies of the supermodes: mode splitting, and (b) difference of the imaginary parts of the eigenfrequencies (i.e., linewidth) of the supermodes. The resonance frequencies of the supermodes are nondegenerate in the  $\mathcal{PT}$ -symmetric regime. In the broken- $\mathcal{PT}$ -symmetry regime, however, they are frequency degenerate.

This Hamiltonian can be diagonalized as

$$H_{1} = (b_{g}^{\dagger} \quad b_{l}^{\dagger})P^{-1} \begin{pmatrix} \Omega_{+} - i\Gamma_{+} & 0\\ 0 & \Omega_{-} - i\Gamma_{-} \end{pmatrix} P \begin{pmatrix} b_{g}\\ b_{l} \end{pmatrix}, \tag{A4}$$

where the transformation matrix P is defined by

$$P = \frac{\binom{g_{mm} \quad [(\Omega_{+} - \Omega_{0}) - i(\Gamma_{+} - \Gamma_{l})]}{g_{mm} \quad [(\Omega_{-} - \Omega_{0}) - i(\Gamma_{-} - \Gamma_{l})]}}{\sqrt{(\Omega_{\pm} - \Omega_{0})^{2} + (\Gamma_{\pm} - \Gamma_{l})^{2} + g_{mm}^{2}}}.$$
 (A5)

Consequently we have

$$\begin{pmatrix} b_+ \\ b_- \end{pmatrix} = P \begin{pmatrix} b_g \\ b_l \end{pmatrix} \tag{A6}$$

as the mechanical supermodes formed by the coupling of the resonators. These supermodes  $b_{\pm}$  are characterized by the eigenfrequencies  $\Omega_{\pm}$  and damping rates  $\Gamma_{\pm}$ .

For this mechanical  $\mathcal{PT}$ -symmetric system, there are two different regimes (see Fig. 7):

(i)  $\mathcal{P}\mathcal{T}$ -symmetric regime where

$$\Gamma = \frac{(\Gamma_l + \Gamma_g)}{2} \leqslant g_{mm},\tag{A7}$$

and the two supermodes  $b_+$  and  $b_-$  are nondegenerate in their resonance frequencies (i.e., real part of their complex eigenfrequencies) given by

$$\Omega_{\pm} = \Omega_0 \pm \beta = \Omega_0 \pm \sqrt{g_{mm}^2 - \Gamma^2}.$$
 (A8)

The damping rates of the supermodes (i.e., linewidths of the resonances; imaginary part of their complex eigenfrequencies) are the same and equal to

$$\Gamma_{\pm} = \chi = \frac{\Gamma_l - \Gamma_g}{2}.$$
 (A9)

(ii) Broken- $\mathcal{P}\mathcal{T}$ -symmetry regime where

$$\Gamma = \frac{\Gamma_l + \Gamma_g}{2} > g_{mm}. \tag{A10}$$

The two supermodes  $b_+$  and  $b_-$  are degenerate in their resonance frequencies

$$\Omega_{\pm} = \Omega_0, \tag{A11}$$

and their damping rates are different:

$$\Gamma_{+} = \chi \mp i\beta. \tag{A12}$$

Now let us consider the nonlinear Kerr term in Eq. (A1). Using Eq. (A6) we find

$$b_{l} = \frac{\sqrt{(\Omega_{+} - \Omega_{0})^{2} + (\Gamma_{+} - \Gamma_{l})^{2} + g_{mm}^{2}}}{(\Omega_{+} - \Omega_{-}) - i(\Gamma_{+} - \Gamma_{-})} b_{+}$$

$$-\frac{\sqrt{(\Omega_{-} - \Omega_{0})^{2} + (\Gamma_{-} - \Gamma_{l})^{2} + g_{mm}^{2}}}{(\Omega_{+} - \Omega_{-}) - i(\Gamma_{+} - \Gamma_{-})} b_{-}$$

$$= \beta_{l+}b_{+} + \beta_{l-}b_{-}.$$

By substituting the above equation into the last term on the right-hand side of Eq. (A1) and dropping the nonresonant terms, we can rewrite the nonlinear Kerr term of Eq. (A1) as

$$H_{nl} = (|\beta_{l+}|^2 b_+^{\dagger} b_+ + |\beta_{l-}|^2 b_-^{\dagger} b_-)^2. \tag{A13}$$

The self-Kerr terms  $|\beta_{l+}|^4(b_+^{\dagger}b_+)^2$  and  $|\beta_{l-}|^4(b_-^{\dagger}b_-)^2$  only lead to a frequency shift of the two supermodes and thus are less important. The cross-Kerr term

$$H'_{nl} = |\beta_{l+}|^2 |\beta_{l-}|^2 (b_+^{\dagger} b_+) (b_-^{\dagger} b_-) = \mu'(b_+^{\dagger} b_+) (b_-^{\dagger} b_-)$$
 (A14)

is more important and leads to the redistribution of the nonlinear effect among the two supermodes. From Eqs. (A7)–(A9), the nonlinear coefficient  $2|\beta_{l+}|^2|\beta_{l-}|^2$  can be represented in the broken- $\mathcal{PT}$  regime as  $\mu_b'$ , and in the  $\mathcal{PT}$ -symmetric regime as  $\mu_a'$ .

$$\mu_b' = \mu \frac{\Gamma^2 g_{mm}^2}{\left(\Gamma^2 - g_{mm}^2\right)^2}, \quad \mu_s' = \mu \frac{g_{mm}^4}{\left(\Gamma^2 - g_{mm}^2\right)^2}.$$
 (A15)

As was observed in photonic experiments [62,78], in the broken- $\mathcal{PT}$  regime the two supermodes  $b_{\pm}$  are degenerate and the field is localized in the gain resonator, and thus the field  $b_l$  is much smaller than  $b_g$ . Therefore, we can omit

the terms related to  $b_l$  in the expressions of the supermodes  $b_{\pm}$  and we have

$$egin{align} b_+ &pprox rac{g_{mm}}{\sqrt{\left(\Omega_+ - \Omega_0
ight)^2 + \left(\Gamma_+ - \Gamma_l
ight)^2 + g_{mm}^2}} b_g, \ b_- &pprox rac{g_{mm}}{\sqrt{\left(\Omega_- - \Omega_0
ight)^2 + \left(\Gamma_- - \Gamma_l
ight)^2 + g_{mm}^2}} b_g. \end{align}$$

Subsequently, we find that the cross-Kerr term given in Eq. (A14) can induce a self-Kerr effect in the gain resonator

$$H'_{nl} = \mu \frac{g_{mm}^4}{4(\Gamma^2 - g_{mm}^2)^2} (b_g^{\dagger} b_g)^2.$$
 (A16)

Clearly, when  $\Gamma \approx g_{mm}$  (in the vicinity of the spontaneous  $\mathcal{P}\mathcal{T}$ -symmetry breaking point: the  $\mathcal{P}\mathcal{T}$ -phase transition point), this self-Kerr nonlinearity is greatly enhanced.

### APPENDIX B: UNIDIRECTIONAL PHONON TRANSPORT BY MECHANICAL NONLINEARITY

Let us now present a detailed analysis for finding the unidirectional phonon transport region near the  $\mathcal{P}T$ -transition point. In this case, the gain-loss balance between the active resonator, with annihilation operator  $b_g$ , and the passive resonator, with annihilation operator  $b_l$ , decreases the effective damping rates of the two modes. In the vicinity of the  $\mathcal{P}T$ -phase transition point (i.e.,  $\Gamma \approx g_{mm}$ ), the effective damping rates of the two modes is given by  $\chi = (\Gamma_l - \Gamma_g)/2$ . The coupling between the two mechanical resonators also leads to the transfer of mechanical Kerr nonlinearity from the passive resonator to the active resonator, and this mechanical nonlinearity is strongly enhanced near the  $\mathcal{P}T$ -transition point (i.e.,  $\Gamma \approx g_{mm}$ ). Hereafter we will denote this enhanced mechanical Kerr nonlinearity coefficient as  $\mu_h'$ .

Let us first consider the phonon transport from the passive resonator to the active resonator. Here the phononic field in the passive resonator is generated via an phononic input field with strength  $\varepsilon_d$  and frequency  $\Omega_d$ . Using the standard input-output formalism [79,80], the output field of the active mechanical resonator is found as  $b_{\text{out}} = \chi^{1/2} b_g$ , which shows that the output field is proportional to the intracavity field  $b_g$ , if we omit the vacuum fluctuations in the input field. Thus the transmission from passive to active resonator is given by

$$T_{l\to g}(\delta) = \chi n_g / |\varepsilon_d|^2,$$
 (B1)

where  $n_g$  represents the steady-state value of the intracavity phonon number in the active resonator. From the steady-state solution of the equations of motion for the coupled mechanical resonator system, we find that  $n_g$  satisfies

$$\tilde{\mu}^2 n_g^3 - 2\tilde{\mu}\tilde{\Omega}n_g^2 + (\tilde{\Gamma}^2 + \tilde{\Omega}^2)n_g - \tilde{n}_{\text{in}} = 0, \quad (B2)$$

where

$$\begin{split} \tilde{\Gamma} &= \left(\chi^2 + \delta^2 + g_{mm}^2\right) \chi, \quad \tilde{\Omega} = (\chi^2 + \delta^2) \Omega_0 - g_{mm}^2 \delta, \\ \tilde{\mu} &= (\chi^2 + \delta^2) \mu_b', \quad \tilde{n}_{\rm in} = |\varepsilon_d|^2 g_{mm}^2 (\chi^2 + \delta^2). \end{split}$$

The algebraic equation (B2) has three or one root depending on the system parameters, and one of the roots is unstable if the algebraic equation (B2) has three roots. When we increase the detuning  $\delta = \Omega_0 - \Omega_d$ , such that

$$\frac{\Omega_0 - (g_{mm}^2 \delta)/(\chi^2 + \delta^2)}{\chi(\chi^2 + \delta^2 + g_{mm}^2)/(\chi^2 + \delta^2)} = \sqrt{3},$$
(B3)

or equivalently,

$$\delta = \delta_{\text{max}} = \frac{g_{mm}^2 + \sqrt{g_{mm}^4 + 4(\sqrt{3}\chi^3 - \chi^2\Omega_0 + \sqrt{3}g_{mm}^2\chi)(\Omega_0 - \sqrt{3}\chi)}}{2(\Omega_0 - \sqrt{3}\chi)},$$
(B4)

the system enters the bistable regime. In fact, when  $\delta \leqslant \delta_{\rm max}$ , the algebraic equation has three branches of solutions. However, two branches of solutions disappear when  $\delta > \delta_{\rm min}$  (see Ref. [81] and the supplementary materials of Ref. [82]). In this case, the transmittance of the photon transport  $T_{l\to g}(\delta)$  changes suddenly from a high value to a low value. Noting that  $g_{mm} \gg \chi$  near the  $\mathcal{PT}$ -breaking point, the critical detuning  $\delta_{\rm max}$  can be approximately estimated to be

$$\delta_{\text{max}} = \frac{g_{mm}^2}{\Omega_0 - \sqrt{3}\chi}.$$
 (B5)

Let us now consider the phonon transport from the active mechanical resonator to the passive one. The driving field with strength  $\varepsilon_d$  and frequency  $\Omega_d$  is fed into the gain resonator in this case. Following the same discussion and approach as for the previous case, it can be shown that a bistability-induced phase transition occurs when the detuning  $\delta = \Omega_0 - \Omega_d$  satisfies

$$\frac{\delta - (g_{mm}^2 \Omega_0) / (\chi^2 + \Omega_0^2)}{\chi (\chi^2 + \Omega_0^2 + g_{mm}^2) / (\chi^2 + \Omega_0^2)} = \sqrt{3},$$
 (B6)

or equivalently,

$$\delta = \delta_{\min} = \frac{\sqrt{3}(\chi^2 + \Omega_0^2 + g_{mm}^2)\chi + g_{mm}^2\Omega_0}{\chi^2 + \Omega_0^2}.$$
 (B7)

Near the  $\mathcal{PT}$ -breaking point,  $\chi \ll g_{mm}$ ,  $\Omega_0$ , and thus  $\delta_{\min}$  can be approximately estimated to be

$$\delta_{\min} = \frac{g_{mm}^2 \Omega_0}{\chi^2 + \Omega_0^2}.$$
 (B8)

Combing Eqs. (B5) and (B8), we find that when the detuning  $\delta$  is within the following region:

$$[\delta_{\min}, \delta_{\max}] = \left[ \frac{g_{mm}^2 \Omega_0}{\Omega_0^2 + \chi^2}, \frac{g_{mm}^2}{\Omega_0 - \sqrt{3}\chi} \right], \tag{B9}$$

it is possible to observe the unidirectional phonon transport, i.e., the phonon transport from the passive resonator to the active resonator is allowed, whereas the phonon transport from the active resonator to the passive resonator is blocked.

Figure 8(a) shows the transmittance functions  $T_{l\to g}(\delta)$  and  $T_{g\to l}(\delta)$  as a function of the detuning  $\delta$ . It is (as explained in the main text) clear that there is a unidirectional phonon transport region when the detuning is up-scanned from smaller to larger detuning. We also show in Fig. 8(b) the rectification ratios for up-scanning and down-scanning the detuning  $\delta$ . Similar to our previous discussions, a nonreciprocal region can be observed

for the up-scanning process, while it disappears for the down-scanning process, and a high rectification-ratio, larger than 30 dB, can be obtained within the nonreciprocal region.

Up to this point, we do not consider the amplitude of the input field. Let us assume that the detuning  $\delta$  is fixed and is within the detuning region given by Eq. (B9). We then vary the amplitude of the input field to show the bistability and the hysteresis in the transmittance functions. Let us first assume that  $\delta > g_{mm}$ . If we consider the phonon transport from the passive resonator to the active resonator, we can obtain an algebraic equation similar to that given in Eq. (B2). The bistable transition point corresponds to the stationary points of

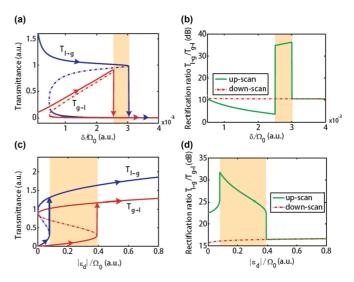


FIG. 8. (Color online) Bistability curves and unidirectional phonon-transport regions. (a) Transmittances as a function of the detuning frequency  $\delta$ , when the input field amplitude is fixed at  $\varepsilon_d$ . (b) Rectification ratio for the bidirectional phonon transport versus the detuning  $\delta$ : A rectification ratio larger than 30 dB can be obtained when the detuning is up-scanned to enter the unidirectional phonon transport region. (c) Transmittances as function of the intensity of the input field when the detuning frequency  $\delta$  is fixed and its value is taken within the unidirectional phonon transport region in (a). The blue and red curves represent the power transmittances from the passive to the active resonator  $T_{l \to g}$  and from the active to the passive resonator  $T_{g\rightarrow l}$ . The solid and dashed parts on each curve denote the stable and unstable solutions of the bistable system. The unstable solutions cannot be observed in the output and thus lead to sudden transitions (black solid arrows) in the transmittance functions. (d) Rectification ratios versus normalized amplitude of the input field for fixed detuning  $\delta$ . The melon-colored shaded areas denote the unidirectional transport regions.

the function

$$f(n_g) = \tilde{\mu}^2 n_g^3 - 2\tilde{\mu}\tilde{\Omega}n_g^2 + (\tilde{\Gamma}^2 + \tilde{\Omega}^2)n_g. \tag{B10}$$

By setting  $f'(n_g) = 0$ , the stationary point of  $f(n_g)$  can be found as

$$n_g^* = \left[2\tilde{\mu}\tilde{\Omega} - \sqrt{4\tilde{\mu}^2\tilde{\Omega}^2 - 3\tilde{\mu}^2(\tilde{\Gamma}^2 + \tilde{\Omega}^2)}\right](3\tilde{\mu}^2)^{-1}.$$
 (B11)

The upper bound of the unidirectional phonon transport region is given by

$$|\varepsilon_{\text{max}}|^2 = \frac{f(n_g^*)}{g_{mm}^2(\chi^2 + \delta^2)} = \frac{2\tilde{\Omega}(\tilde{\Gamma}^2 + \tilde{\Omega}^2)}{9\tilde{\mu}g_{mm}^2(\chi^2 + \delta^2)} + \frac{(6\tilde{\Gamma}^2 - 2\tilde{\Omega}^2)}{9g_{mm}^2(\chi^2 + \delta^2)} \left[ \frac{2\tilde{\mu}\tilde{\Omega} - \sqrt{4\tilde{\mu}^2\tilde{\Omega}^2 - 3\tilde{\mu}^2(\tilde{\Gamma}^2 + \tilde{\Omega}^2)}}{3\tilde{\mu}^2} \right].$$

Near the  $\mathcal{PT}$ -transition point, we have  $\delta$ ,  $g_{mm} \gg \chi$ , and thus it can be approximately estimated that

$$|\varepsilon_{\text{max}}|^2 \approx \frac{2(\delta^2 + g_{mm}^2)^2}{9\mu_B'g_{mm}^2\delta}.$$
 (B12)

Let us now consider the case of phonon transport from the active resonator to the passive resonator when the amplitude of the input field is varied and the detuning is kept fixed. In this case we obtain

$$\tilde{\tilde{\mu}}^2 n_g^3 - 2\tilde{\tilde{\mu}} \tilde{\tilde{\Omega}} n_g^2 + (\tilde{\tilde{\Gamma}}^2 + \tilde{\tilde{\Omega}}^2) n_g - \tilde{\tilde{n}}_{\rm in} = 0, \tag{B13}$$

where

$$\tilde{\Gamma} = (\chi^2 + \Omega_0^2 + g_{mm}^2)\chi, \quad \tilde{\Omega} = (\chi^2 + \Omega^2)\delta - g_{mm}^2\Omega_0,$$

$$\tilde{\mu} = (\chi^2 + \Omega_0^2)\mu_h', \quad \tilde{n}_{\text{in}} = (\chi^2 + \delta^2)^2|\varepsilon_d|^2.$$

Similar to Eq. (B10), the bistable transition point can be found by calculating the stationary points of the function

$$f(n_g) = \tilde{\tilde{\mu}}^2 n_g^3 - 2\tilde{\tilde{\mu}}\tilde{\tilde{\Omega}}n_g^2 + (\tilde{\tilde{\Gamma}}^2 + \tilde{\tilde{\Omega}}^2)n_g,$$
 (B14)

which leads to

$$\tilde{n}_g^* = [2\tilde{\tilde{\mu}}\tilde{\tilde{\Omega}} - \sqrt{4\tilde{\tilde{\mu}}^2\tilde{\tilde{\Omega}}^2 - 3\tilde{\tilde{\mu}}^2(\tilde{\tilde{\Gamma}}^2 + \tilde{\tilde{\Omega}}^2)}](3\tilde{\tilde{\mu}}^2)^{-1}. \quad (B15)$$

The lower bound of the unidirectional phonon transport region is then given by

$$\begin{split} |\varepsilon_{\min}|^2 &= \frac{\tilde{f}(\tilde{n}_g^*)}{(\chi^2 + \delta^2)^2} = \frac{2\tilde{\tilde{\Omega}}(\tilde{\tilde{\Gamma}}^2 + \tilde{\tilde{\Omega}}^2)}{9\tilde{\tilde{\mu}}(\chi^2 + \delta^2)^2} + \frac{(6\tilde{\tilde{\Gamma}}^2 - 2\tilde{\tilde{\Omega}}^2)}{9g_{mm}^2(\chi^2 + \delta^2)} \\ &\times \left[ \frac{2\tilde{\tilde{\mu}}\tilde{\tilde{\Omega}} - \sqrt{4\tilde{\tilde{\mu}}^2\tilde{\tilde{\Omega}}^2 - 3\tilde{\tilde{\mu}}^2(\tilde{\tilde{\Gamma}}^2 + \tilde{\tilde{\Omega}}^2)}}{3\tilde{\tilde{\mu}}^2} \right]. \end{split}$$

Near the  $\mathcal{PT}$ -transition point we have  $\delta$ ,  $g_{mm} \gg \chi$ , and it can be approximately estimated that

$$|\varepsilon_{\min}|^2 \approx \frac{2(\delta^2 + g_{mm}^2)^2}{9u_i'\delta^3}.$$
 (B16)

We thus conclude that nonreciprocal phonon transport takes place if the amplitude of the input is within the region

$$|\varepsilon_d|^2 \in \left[\frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'\delta^3}, \frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'g_{mm}^2\delta}\right].$$
 (B17)

Similarly, when  $\delta \leqslant g_{mm}$ , the nonreciprocal region for the amplitude of the input field can be written as

$$|\varepsilon_d|^2 \in \left[\frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'g_{mm}^2\delta}, \frac{2(\delta^2 + g_{mm}^2)^3}{9\mu_b'\delta^3}\right].$$
 (B18)

In Fig. 8(c) we present the transmittances as a function of the amplitude of the input field when the detuning is kept fixed within the unidirectional transport region given in Eq. (B9). We see that the lower stable branches of the bistable curves shown in Fig. 8(c) (the parts of the bistable curves before the bistable transitions occur) increase when we increase the intensity of the input field. This decreases the rectification, as shown in Fig. 8(d).

# APPENDIX C: CAN THIS SYSTEM BE USED AS A PHONON ISOLATOR?

In order to check the performance of the proposed system as an isolator for phonons, we study the system considering that phonons are injected in the system in both directions, that is simultaneously at the passive and active resonator sides. If the system exhibits unidirectional phonon transport under this condition, then the proposed system can be used as an isolator.

The equations of motion of the system for this case can be written as

$$\begin{split} \dot{b}_{l} &= -(\chi + i\delta_{l})b_{l} - ig_{mm}b_{g} + i\varepsilon_{l}, \\ \dot{b}_{g} &= -(\chi + i\delta_{g})b_{g} - i\mu'_{b}(b_{g}^{\dagger}b_{g})b_{g} - ig_{mm}b_{l} + i\varepsilon_{g}, \end{split}$$
 (C1)

where the last terms on the right-hand sides of Eq. (C1) denote the input fields. The steady-state solution of Eq. (C1) leads to

$$\bar{\mu}^2 n_g^3 - 2\bar{\mu}\bar{\Omega}n_g^2 + (\bar{\Gamma}^2 + \bar{\Omega}^2)n_g - \bar{n}_{\rm in} = 0, \eqno(C2)$$

where

$$\bar{\Gamma} = (\chi^2 + \delta_l^2 + g_{mm}^2)\chi, \quad \bar{\mu} = (\chi^2 + \delta_l^2)\mu_b', 
\bar{\Omega} = (\chi^2 + \delta_l^2)\delta_g - g_{mm}^2\delta_l, 
\bar{n}_{in} = |\varepsilon_l|^2 g_{mm}^2 (\chi^2 + \delta_l^2) + (\chi^2 + \delta_l^2)^2 |\varepsilon_g|^2.$$

Let us first fix  $\varepsilon_l$ ,  $\varepsilon_g$ ,  $\delta_g$ , and vary the detuning  $\delta_l = \delta$ . In this case the bistable transitions for both directions occur when the

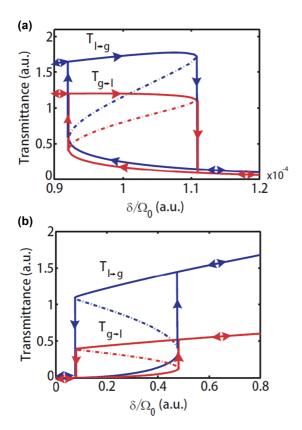


FIG. 9. (Color online) Bistability curves for the mechanical  $\mathcal{PT}$  system when phonons are input simultaneously in both directions. (a) Transmittances as functions of the detuning frequency  $\delta$  when the input field amplitude is fixed at  $\varepsilon_d$ . (b) Transmittances as functions of the amplitude of the input field when the detuning frequency  $\delta$  is fixed. The blue and red curves represent the power transmittance functions  $T_{l\to g}$  and  $T_{g\to l}$ . The solid and dashed parts on each curve denote the stable and unstable solutions of the bistable systems. The unstable solutions cannot be observed in the output and thus lead to sudden transitions in the transmittance functions.

detuning  $\delta$  satisfies

$$\frac{\delta_g - (g_{mm}^2 \delta)/(\chi^2 + \delta^2)}{\chi(\chi^2 + \delta^2 + g_{mm}^2)/(\chi^2 + \delta^2)} = \sqrt{3}.$$
 (C3)

When the detuning is up-scanned from smaller to larger detuning values, the bistable transition occurs for

$$\delta = \sqrt{\frac{g_{mm}^4}{4(\delta_g - \sqrt{3}\chi)^2} + \frac{(\sqrt{3}\chi^3 - \chi^2\delta_g + \sqrt{3}g_{mm}^2\chi)}{(\delta_g - \sqrt{3}\chi)}} + \frac{g_{mm}^2}{2(\delta_g - \sqrt{3}\chi)}.$$
 (C4)

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When the detuning  $\delta$  is down-scanned from larger to smaller detuning values, the bistable transition occur at

$$\delta = -\sqrt{\frac{g_{mm}^4}{4(\delta_g - \sqrt{3}\chi)^2} + \frac{\left(\sqrt{3}\chi^3 - \chi^2\delta_g + \sqrt{3}g_{mm}^2\chi\right)}{(\delta_g - \sqrt{3}\chi)}} + \frac{g_{mm}^2}{2(\delta_g - \sqrt{3}\chi)}.$$
(C5)

The transmittances presented in Fig. 9(a) clearly show the bistable operation. A close look at Fig. 9(a) reveals that the transition from the bistable region to the stable trajectories takes place at the same points for both directions. We cannot find a detuning region within which transport in one direction is allowed and the transport in the other direction is prevented. Thus, we conclude that when phonons are injected simultaneously at both input ports, we cannot see a unidirectional operation. Consequently it is impossible to use this system as an isolator for phonons.

Let us now fix  $\delta_l$ ,  $\delta_g$ ,  $\varepsilon_g$ , and vary  $\varepsilon_l = \varepsilon_d$ , to check the possibility of providing a phonon isolator. The bistable transition point is just the stationary points of the function

$$\bar{f}(n_g) = \bar{\mu}^2 n_g^3 - 2\bar{\mu}\bar{\Omega}n_g^2 + (\bar{\Gamma}^2 + \bar{\Omega}^2)n_g - |\varepsilon_g|^2.$$
 (C6)

By setting  $\bar{f}'(n_g) = 0$ , we find

$$\begin{split} \bar{n}_{g1}^* &= [2\bar{\mu}\bar{\Omega} + \sqrt{4\bar{\mu}^2\bar{\Omega}^2 - 3\bar{\mu}^2(\bar{\Gamma}^2 + \bar{\Omega}^2)}](3\bar{\mu}^2)^{-1}, \\ \bar{n}_{g2}^* &= [2\bar{\mu}\bar{\Omega} - \sqrt{4\bar{\mu}^2\bar{\Omega}^2 - 3\bar{\mu}^2(\bar{\Gamma}^2 + \bar{\Omega}^2)}](3\bar{\mu}^2)^{-1}, \end{split}$$

The bistable transition occurs at

$$|\varepsilon_d|^2 = \frac{f(n_{g1}^*)}{g_{mm}^2(\chi^2 + \delta_l^2)} \tag{C7}$$

when the amplitude of the input field  $\varepsilon_d$  is up-scanned and for

$$|\varepsilon_d|^2 = \frac{f(n_{g2}^*)}{g_{mm}^2(\chi^2 + \delta_l^2)}$$
 (C8)

when the amplitude of the input field is down-scanned (see Fig. 9). For this case too, we do not see a unidirectional phonon transport region if we feed the inputs at the active and passive resonators sides simultaneously. Thus we conclude that although the proposed system can be used as phonon diode allowing nonreciprocal phonon transport, it cannot function as an isolator for phonons.

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